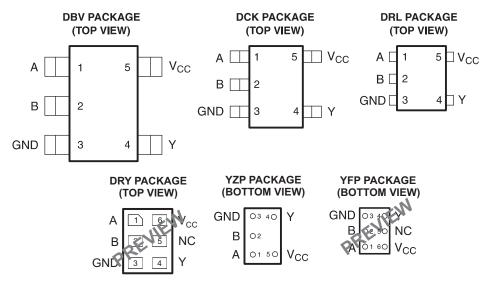


FEATURES

- Available in the Texas Instruments NanoFree™ Package
- Low Static-Power Consumption ($I_{CC} = 0.9 \mu A$ Maximum)
- Low Dynamic-Power Consumption (C_{pd} = 4.3 pF Typ at 3.3 V)
- Low Input Capacitance (C_i = 1.5 pF Typical)
- Low Noise Overshoot and Undershoot <10% of V_{CC}
- Ioff Supports Partial-Power-Down Mode Operation
- Schmitt-Trigger Action Allows Slow Input **Transition and Better Switching Noise** Immunity at the Input (V_{hys} = 250 mV Typical at 3.3 V)
- Wide Operating V_{CC} Range of 0.8 V to 3.6 V

- **Optimized for 3.3-V Operation**
- 3.6-V I/O Tolerant to Support Mixed-Mode **Signal Operation**
- t_{pd} = 4.3 ns Maximum at 3.3 V
- Suitable for Point-to-Point Applications
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22
 - 2000-V Human-Body Model (A114-B, Class II)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)
- ESD Protection Exceeds ±5000 V With **Human-Body Model**



See mechanical drawings for dimensions.

DESCRIPTION/ORDERING INFORMATION

The AUP family is TI's premier solution to the industry's low-power needs in battery-powered portable applications. This family ensures a very low static- and dynamic-power consumption across the entire V_{CC} range of 0.8 V to 3.6 V, resulting in increased battery life (see Figure 1). This product also maintains excellent signal integrity (see the very low undershoot and overshoot characteristics shown in Figure 2).

This single 2-input positive-AND gate performs the Boolean function $Y = A \bullet B$ or $Y = \overline{A + B}$ in positive logic.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet. NanoFree is a trademark of Texas Instruments.



DESCRIPTION/ORDERING INFORMATION (CONTINUED)

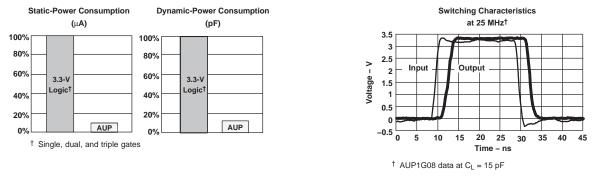


Figure 1. AUP - The Lowest-Power Family



NanoFree[™] package technology is a major breakthrough in IC packaging concepts, using the die as the package.

This device is fully specified for partial-power-down applications using I_{off}. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

ORDERING INFORMATION

T _A	PACKAGE ⁽¹⁾⁽²⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING ⁽³⁾
	NanoFree™ – WCSP (DSBGA) 0.23-mm Large Bump – YFP (Pb-free)	Reel of 3000	SN74AUP1G08YFPR	PREVIEW
	NanoFree™ – WCSP (DSBGA) 0.23-mm Large Bump – YZP (Pb-free)	Reel of 3000	SN74AUP1G08YZPR	HE_
–40°C to 85°C	SON – DRY	Reel of 5000	SN74AUP1G08DRYR	PREVIEW
	SOT (SOT-23) – DBV	Reel of 3000	SN74AUP1G08DBVR	H08_
	SOT (SC-70) – DCK	Reel of 3000	SN74AUP1G08DCKR	HE
	SOT (SOT-553) – DRL	Reel of 4000	SN74AUP1G08DRLR	· · · · _

(1) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

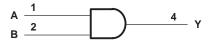
(2) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

(3) DBV/DCK/DRL/DRY: The actual top-side marking has one additional character that designates the assembly/test site. YFP/YZP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the assembly/test site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, · = Pb-free).

INPU	JTS	OUTPUT
Α	В	Y
L	L	L
L	н	L
н	L	L
н	н	н

FUNCTION TABLE

LOGIC DIAGRAM (POSITIVE LOGIC)





Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT	
V _{CC}	Supply voltage range		-0.5	4.6	V	
VI	Input voltage range ⁽²⁾		-0.5	4.6	V	
Vo	Voltage range applied to any output in the h	high-impedance or power-off state ⁽²⁾	-0.5	4.6	V	
Vo	Output voltage range in the high or low state	e ⁽²⁾	-0.5	V _{CC} + 0.5	V	
I _{IK}	Input clamp current	V ₁ < 0		-50	mA	
I _{OK}	Output clamp current	V _O < 0		-50	mA	
I _O	Continuous output current		±20	mA		
	Continuous current through V_{CC} or GND			±50	mA	
		DBV package		206		
		DCK package		252		
0	De alta sua di anno al ince a dan a a (3)	DRL package		142	0000	
θ_{JA}	Package thermal impedance ⁽³⁾	DRY package		234	°C/W	
		YFP package		132	1	
		YZP package		132		
T _{stg}	Storage temperature range		-65	150	°C	

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability. (2) The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.
(3) The package thermal impedance is calculated in accordance with JESD 51-7.

SN74AUP1G08 LOW-POWER SINGLE 2-INPUT POSITIVE-AND GATE

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Recommended Operating Conditions⁽¹⁾

			MIN	MAX	UNIT	
V _{CC}	Supply voltage		0.8	3.6	V	
		V _{CC} = 0.8 V	V _{CC}			
v		$V_{CC} = 1.1 \text{ V to } 1.95 \text{ V}$	$0.65 imes V_{CC}$		V	
V _{IH}	High-level input voltage	V_{CC} = 2.3 V to 2.7 V	1.6		v	
		V_{CC} = 3 V to 3.6 V	2			
		V _{CC} = 0.8 V		0		
V		$V_{CC} = 1.1 \text{ V to } 1.95 \text{ V}$		$0.35 \times V_{CC}$	V	
V _{IL}	Low-level input voltage	V_{CC} = 2.3 V to 2.7 V		0.7	v	
		V_{CC} = 3 V to 3.6 V		0.9		
VI	Input voltage		0	3.6	V	
Vo	Output voltage		0	V _{CC}	V	
	High-level output current	V _{CC} = 0.8 V		-20	μA	
		V _{CC} = 1.1 V		-1.1		
		High lovel output current	High lovel output ourrent	$V_{CC} = 1.4 V$		-1.7
I _{OH}	High-level output current	V _{CC} = 1.65		-1.9	mA	
		V _{CC} = 2.3 V		-3.1		
		$V_{CC} = 3 V$		-4		
		$V_{CC} = 0.8 V$		20	μA	
		$V_{CC} = 1.1 V$		1.1		
		$V_{CC} = 1.4 V$		1.7		
I _{OL}	Low-level output current	$V_{CC} = 1.65 V$		1.9	mA	
		V _{CC} = 2.3 V		3.1		
		$V_{CC} = 3 V$		4		
Δt/Δv	Input transition rise or fall rate	V_{CC} = 0.8 V to 3.6 V		200	ns/V	
T _A	Operating free-air temperature		-40	85	°C	

 All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



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Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

DADAMETER	TEST CONDITIONS	V	TA	= 25°C	T _A = −40°C	to 85°C	UNIT				
PARAMETER	TEST CONDITIONS	V _{cc}	MIN	TYP MAX	MIN	MAX	UNIT				
	I _{OH} = -20 μA	0.8 V to 3.6 V	V _{CC} – 0.1		V _{CC} – 0.1						
	I _{OH} = -1.1 mA	1.1 V	$0.75 imes V_{CC}$		$0.7 \times V_{CC}$						
	I _{OH} = -1.7 mA	1.4 V	1.11		1.03						
	I _{OH} = -1.9 mA	1.65 V	1.32		1.3						
V _{OH}	I _{OH} = -2.3 mA	0.0.1/	2.05		1.97		V				
	I _{OH} = -3.1 mA	2.3 V	1.9		1.85						
	I _{OH} = -2.7 mA	2.1/	2.72		2.67						
	I _{OH} = -4 mA	3 V	2.6		2.55						
	I _{OL} = 20 μA	0.8 V to 3.6 V		0.1		0.1					
	I _{OL} = 1.1 mA	1.1 V		$0.3 imes V_{CC}$		$0.3 imes V_{CC}$					
V _{OL}	I _{OL} = 1.7 mA	1.4 V		0.31		0.37					
	I _{OL} = 1.9 mA	1.65 V		0.31		0.35	V				
	I _{OL} = 2.3 mA	221/		0.31		0.33					
	I _{OL} = 3.1 mA	2.3 V		0.44		0.45					
	I _{OL} = 2.7 mA	2.1/		0.31		0.33					
	I _{OL} = 4 mA	3 V		0.44		0.45					
II A or B input	$V_1 = GND$ to 3.6 V	0 V to 3.6 V		0.1		0.5	μA				
l _{off}	V_{I} or V_{O} = 0 V to 3.6 V	0 V		0.2		0.6	μA				
Δl _{off}	V_{I} or $V_{O} = 0$ V to 3.6 V	0 V to 0.2 V		0.2		0.6	μA				
I _{cc}		0.8 V to 3.6 V		0.5		0.9	μA				
ΔI _{CC}	$V_{I} = V_{CC} - 0.6 V^{(1)},$ $I_{O} = 0$	3.3 V		40		50	μA				
0		0 V		1.5			~ Г				
C _i	$V_I = V_{CC}$ or GND	3.6 V		1.5			pF				
C _o	V _O = GND	0 V		3			pF				

(1) One input at V_{CC} – 0.6 V, other input at V_{CC} or GND

Switching Characteristics

over recommended operating free-air temperature range, C_L = 5 pF (unless otherwise noted) (see Figure 3 and Figure 4)

PARAMETER	FROM	то	V	T,	₄ = 25°C		T _A = −40°C t	o 85°C	UNIT
FARAMETER	(INPUT)	(OUTPUT)	V _{cc}	MIN	TYP	MAX	MIN	MAX	UNIT
			0.8 V		18				
			1.2 V ± 0.1 V	2.6	7.3	12.8	2.1	15.6	
	A or B	v	1.5 V ± 0.1 V	1.4	5.2	8.7	0.9	10.3	20
t _{pd}	AUB	T	1.8 V ± 0.15 V	1	4.2	6.6	0.5	8.2	ns
			2.5 V ± 0.2 V	1	3	4.4	0.5	5.5	
			$3.3 \text{ V} \pm 0.3 \text{ V}$	1	2.4	3.5	0.5	4.3	

SN74AUP1G08 LOW-POWER SINGLE 2-INPUT POSITIVE-AND GATE

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Switching Characteristics

over recommended operating free-air temperature range, $C_L = 10 \text{ pF}$ (unless otherwise noted) (see Figure 3 and Figure 4)

PARAMETER	FROM	то	V	T,	₄ = 25°C	;	T _A = −40°C t	o 85°C	UNIT
FARAINETER	(INPUT)	(OUTPUT)	V _{cc}	MIN	TYP	MAX	MIN	MAX	UNIT
			0.8 V		21				
			1.2 V ± 0.1 V	1.5	8.5	14.7	1	17.2	
	A or B	Y	1.5 V ± 0.1 V	1	6.2	10	0.5	11.3	20
t _{pd}	AUB		1.8 V ± 0.15 V	1	5	7.7	0.5	9	ns
			2.5 V ± 0.2 V	1	3.6	5.2	0.5	6.1	
			3.3 V ± 0.3 V	1	2.9	4.2	0.5	4.7	

Switching Characteristics

over recommended operating free-air temperature range, $C_L = 15 \text{ pF}$ (unless otherwise noted) (see Figure 3 and Figure 4)

PARAMETER	FROM	то	М	T,	_A = 25°C		T _A = −40°C t	o 85°C	UNIT
FARAIVIETER	(INPUT)	(OUTPUT)	V _{cc}	MIN	TYP	MAX	MIN	MAX	UNIT
			0.8 V		24				
			1.2 V ± 0.1 V	3.6	9.9	16.3	3.1	19.9	
	A or B	~	1.5 V ± 0.1 V	2.3	7.2	11.1	1.8	13.2	20
t _{pd}	AUID	T	1.8 V ± 0.15 V	1.6	5.8	8.7	1.1	10.6	ns
			$2.5 \text{ V} \pm 0.2 \text{ V}$	1	4.3	5.9	0.5	7.3	
			$3.3 \text{ V} \pm 0.3 \text{ V}$	1	3.4	4.8	0.5	5.9	

Switching Characteristics

over recommended operating free-air temperature range, C_L = 30 pF (unless otherwise noted) (see Figure 3 and Figure 4)

PARAMETER	FROM	то	V _{cc}	T _A = 25°C			T _A = −40°C to	o 85°C	UNIT
PARAMETER	(INPUT)	(OUTPUT)		MIN	TYP	MAX	MIN	MAX	UNIT
			0.8 V		32.8				
			1.2 V ± 0.1 V	4.9	13.1	20.9	4.4	25.5	ns
	A or D	Y	1.5 V ± 0.1 V	3.4	9.5	14.2	2.9	16.9	
t _{pd}	A or B	ř	1.8 V ± 0.15 V	2.5	7.7	11	2	13.5	
			2.5 V ± 0.2 V	1.8	5.7	7.6	1.3	9.4	
			3.3 V ± 0.3 V	1.5	4.7	6.2	1	7.5	

Operating Characteristics

T_A = 25°C

6

	PARAMETER	TEST CONDITIONS	V _{cc}	TYP	UNIT
			0.8 V	4	
	C Dever dissinction conscitutes		1.2 V ± 0.1 V	4	pF
C		f = 10 MHz	1.5 V ± 0.1 V	4	
C _{pd}	Power dissipation capacitance		1.8 V ± 0.15 V	4	
			2.5 V ± 0.2 V	4.1	
			$3.3 \text{ V} \pm 0.3 \text{ V}$	4.3	

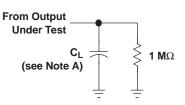
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RUMENTS



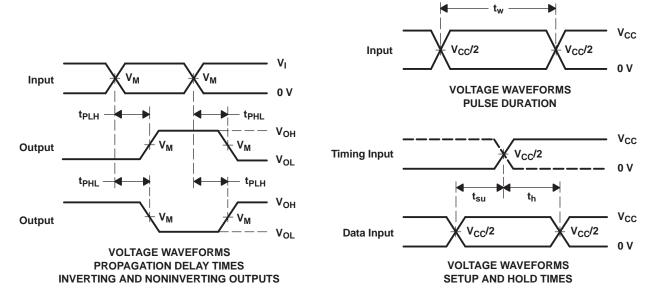
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PARAMETER MEASUREMENT INFORMATION (Propagation Delays, Setup and Hold Times, and Pulse Duration)



LOAD CIRCUIT

	V _{CC} = 0.8 V	V _{CC} = 1.2 V ± 0.1 V	V _{CC} = 1.5 V ± 0.1 V	V _{CC} = 1.8 V ± 0.15 V	V _{CC} = 2.5 V ± 0.2 V	$V_{CC} = 3.3 V \\ \pm 0.3 V$
CL	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF
V _M	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2
VI	V _{CC}	V _{CC}	V _{CC}	V _{CC}	V _{CC}	V _{CC}



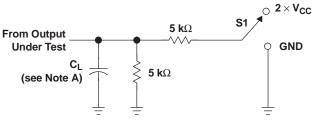
NOTES: A. C_L includes probe and jig capacitance.

- B. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω , slew rate \geq 1 V/ns.
- C. The outputs are measured one at a time, with one transition per measurement.
- D. t_{PLH} and t_{PHL} are the same as t_{pd} .
- E. All parameters and waveforms are not applicable to all devices.

Figure 3. Load Circuit and Voltage Waveforms



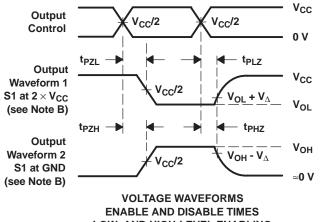
PARAMETER MEASUREMENT INFORMATION (Enable and Disable Times)



TEST	S1
t _{PLZ} /t _{PZL}	$2 \times \mathbf{V}_{CC}$
t _{PHZ} /t _{PZH}	GND

LOAD CIRCUIT

	V _{CC} = 0.8 V	V _{CC} = 1.2 V ± 0.1 V	V _{CC} = 1.5 V ± 0.1 V	V _{CC} = 1.8 V ± 0.15 V	V _{CC} = 2.5 V ± 0.2 V	V _{CC} = 3.3 V ± 0.3 V
CL	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF
V _M	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2
V _I	V _{CC}	V _{CC}	V _{CC}	V _{CC}	V _{CC}	V _{CC}
V _Δ	0.1 V	0.1 V	0.1 V	0.15 V	0.15 V	0.3 V



LOW- AND HIGH-LEVEL ENABLING

- NOTES: A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω , slew rate \geq 1 V/ns.
 - D. The outputs are measured one at a time, with one transition per measurement.
 - E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
 - F. t_{PZL} and t_{PZH} are the same as t_{en} .
 - G. All parameters and waveforms are not applicable to all devices.

Figure 4. Load Circuit and Voltage Waveforms

TEXAS INSTRUMENTS

22-Jul-2008

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Packag Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	n MSL Peak Temp ⁽³⁾
SN74AUP1G08DBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUP1G08DBVRE4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUP1G08DBVRG4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUP1G08DBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUP1G08DBVTE4	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUP1G08DBVTG4	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUP1G08DCKR	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUP1G08DCKRE4	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUP1G08DCKRG4	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUP1G08DCKT	ACTIVE	SC70	DCK	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUP1G08DCKTE4	ACTIVE	SC70	DCK	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUP1G08DCKTG4	ACTIVE	SC70	DCK	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUP1G08DRLR	ACTIVE	SOT	DRL	5	4000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUP1G08DRLRG4	ACTIVE	SOT	DRL	5	4000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUP1G08YZPR	ACTIVE	DSBGA	YZP	5	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details. **TBD:** The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.



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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

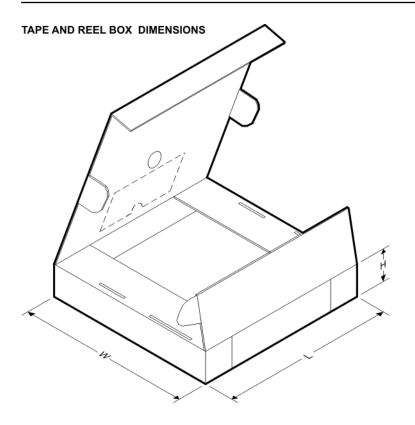


*All dimensions are nominal												
Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AUP1G08DBVR	SOT-23	DBV	5	3000	180.0	9.2	3.23	3.17	1.37	4.0	8.0	Q3
SN74AUP1G08DBVT	SOT-23	DBV	5	250	180.0	9.2	3.23	3.17	1.37	4.0	8.0	Q3
SN74AUP1G08DCKR	SC70	DCK	5	3000	180.0	9.2	2.24	2.34	1.22	4.0	8.0	Q3
SN74AUP1G08DCKT	SC70	DCK	5	250	180.0	9.2	2.24	2.34	1.22	4.0	8.0	Q3
SN74AUP1G08DRLR	SOT	DRL	5	4000	180.0	9.2	1.78	1.78	0.69	4.0	8.0	Q3
SN74AUP1G08YZPR	DSBGA	YZP	5	3000	180.0	8.4	1.02	1.52	0.66	4.0	8.0	Q1



PACKAGE MATERIALS INFORMATION

22-Jul-2008



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AUP1G08DBVR	SOT-23	DBV	5	3000	202.0	201.0	28.0
SN74AUP1G08DBVT	SOT-23	DBV	5	250	202.0	201.0	28.0
SN74AUP1G08DCKR	SC70	DCK	5	3000	202.0	201.0	28.0
SN74AUP1G08DCKT	SC70	DCK	5	250	202.0	201.0	28.0
SN74AUP1G08DRLR	SOT	DRL	5	4000	202.0	201.0	28.0
SN74AUP1G08YZPR	DSBGA	YZP	5	3000	220.0	220.0	34.0

DBV (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.

D. Falls within JEDEC MO-178 Variation AA.



DCK (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES: A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
 - D. Falls within JEDEC MO-203 variation AA.



DRL (R-PDSO-N5)

PLASTIC SMALL OUTLINE



NOTES:

All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994. Α. B. This drawing is subject to change without notice.

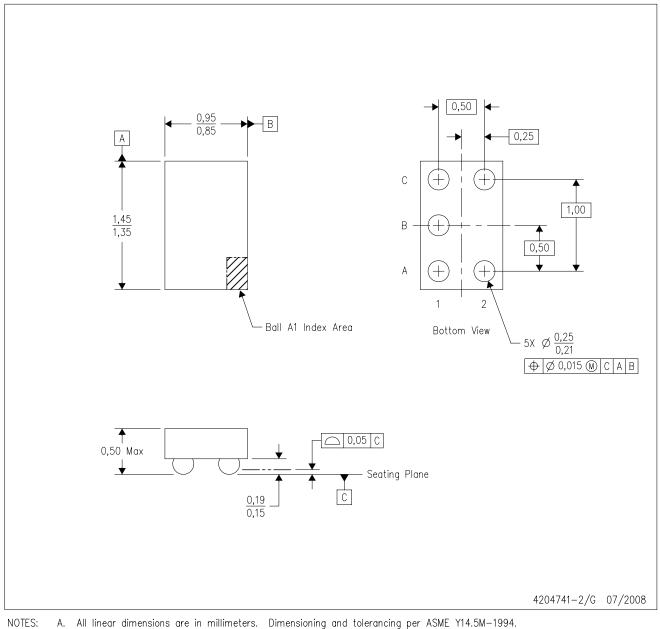
🖄 Body dimensions do not include mold flash, interlead flash, protrusions, or gate burrs. Mold flash, interlead flash, protrusions, or gate burrs shall not exceed 0,15 per end or side.





YZP (R-XBGA-N5)

DIE-SIZE BALL GRID ARRAY



- B. This drawing is subject to change without notice.
- C. NanoFree™ package configuration.
- D. This package is lead-free. Refer to the 5 YEP package (drawing 4204725) for tin-lead (SnPb).

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